

Accurate and Rapid Analysis of High-Impedance Surfaces: Plane-Wave and Surface-Wave Analytical Models

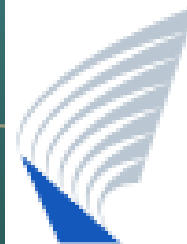
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Outline

- Part I
Analytical Modeling of High Impedance Surfaces
- Part II
Surface Waves on High Impedance Surfaces

Part I

Outline

- **Introduction and Motivation**
- **Series-Resonant Grid Model**
 - ✓ **Jerusalem Cross Array**
 - ✓ **Patch Array**
 - ✓ **Mushroom Array**

Motivation

- **HIS structures with electrically small FSS elements**
 - ✓ Homogenized FSS grids for far-field and near-field sources
- **Metamaterial substrates**
 - ✓ Wire media slabs
 - ✓ Slabs with spherical inclusions
- **Nanotechnology**

Introduction

Analytical modeling of dense FSS grids

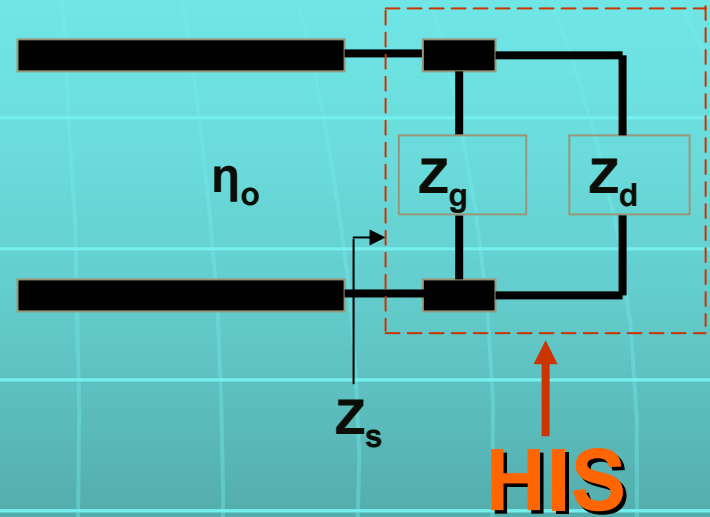
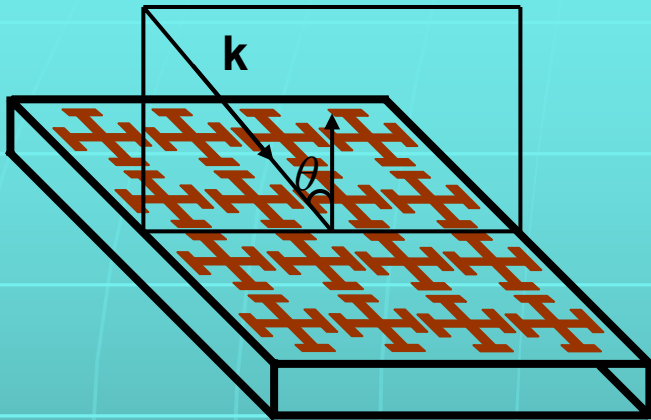
- ✓ Homogenization of impedance surface in terms of effective circuit parameters

Quasi-static approximation of full-wave scattering problem via the averaged impedance boundary condition

- ✓ Parallel resonance of grid and slab surface impedances
- ✓ Single unit cell of periodic grid and a single Floquet mode
- ✓ Babinet principle

Series-Resonant Grid Model

Transmission-Line Network Analysis



Reflection coefficient

$$\Gamma^{TE}(\omega, \theta) = \frac{Z_s \cos \theta - \eta_0}{Z_s \cos \theta + \eta_0}$$

$$\Gamma^{TM}(\omega, \theta) = \frac{Z_s - \eta_0 \cos \theta}{Z_s + \eta_0 \cos \theta}$$

$$Z_s = \frac{Z_g Z_d}{Z_g + Z_d}$$

Parallel resonance

$$X_g(\omega) + X_d(\omega) = 0$$

Dielectric Impedance

TE Polarization

$$Z_d^{TE}(\omega, \theta) = \frac{j\eta_0}{\sqrt{\epsilon_r - \sin^2 \theta}} \tan(k_{nd} h)$$

TM Polarization

$$Z_d^{TM}(\omega, \theta) = \frac{j\eta_0}{\sqrt{\epsilon_r - \sin^2 \theta}} \tan(k_{nd} h) \left(1 - \frac{\sin^2 \theta}{\epsilon_r} \right)$$

Where

$$k_{nd} = \frac{\omega}{c} \sqrt{\epsilon_r - \sin^2 \theta}$$

is the vertical component of the wave vector of the refracted wave

In case of normal incidence $Z_d^{TE}(\omega, 0) = Z_d^{TM}(\omega, 0) = Z_d(\omega, 0)$

- The dielectric impedance is inductive for all grounded substrates with thickness less than $\lambda_d / 4$

Grid Impedance

- The grid impedance is obtained in the quasi-static limit of the full-wave scattering problem via the averaged impedance boundary condition and expressed in terms of effective circuit parameters (effective inductance and effective capacitance)

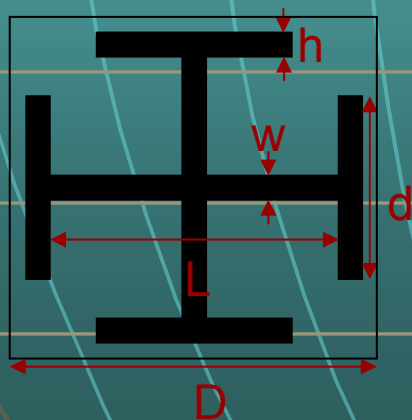
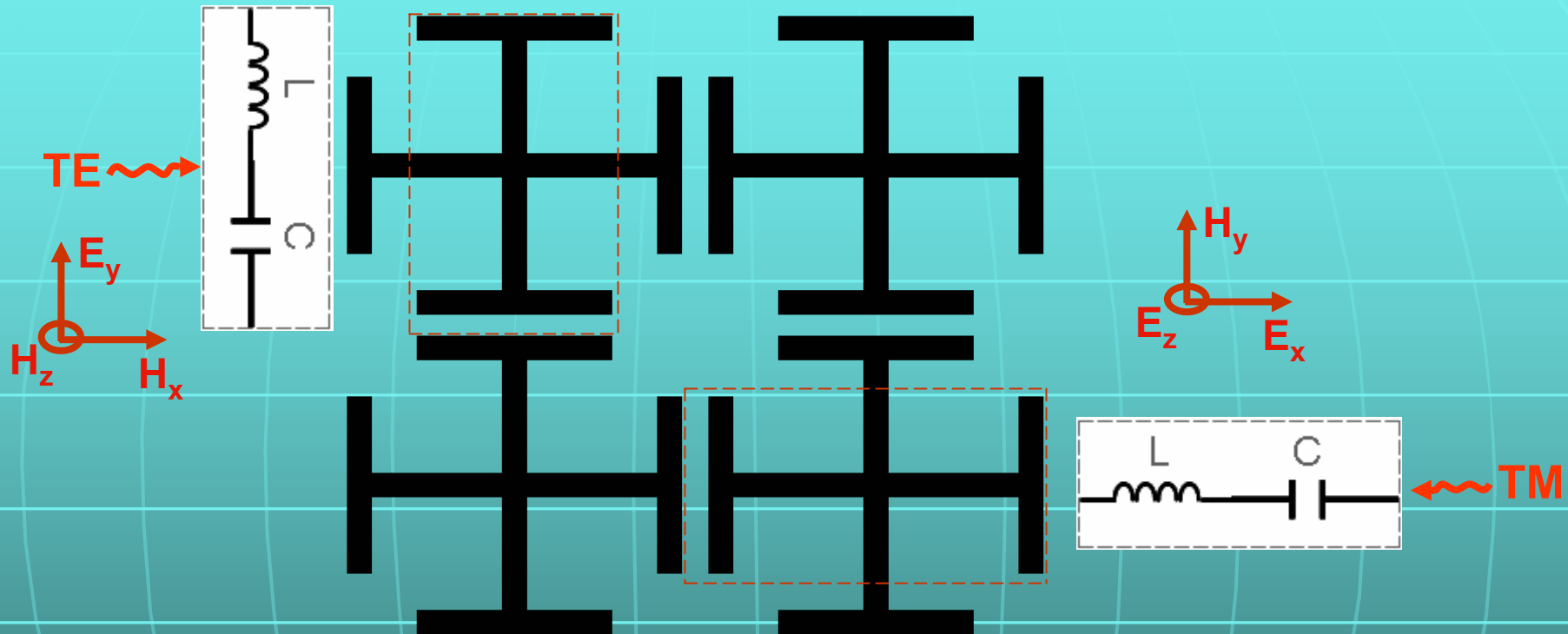
TE Polarization

$$Z_g^{TE}(\omega, \theta) = Z_{g,L}^{TE}(\omega, \theta) + Z_{g,C}^{TE}(\omega, \theta)$$

TM Polarization

$$Z_g^{TM}(\omega, \theta) = Z_{g,L}^{TM}(\omega, \theta) + Z_{g,C}^{TM}(\omega, \theta)$$

Jerusalem Cross Array



$D = 4 \text{ mm}$, $L = 3.5 \text{ mm}$, $d = 2.8 \text{ mm}$

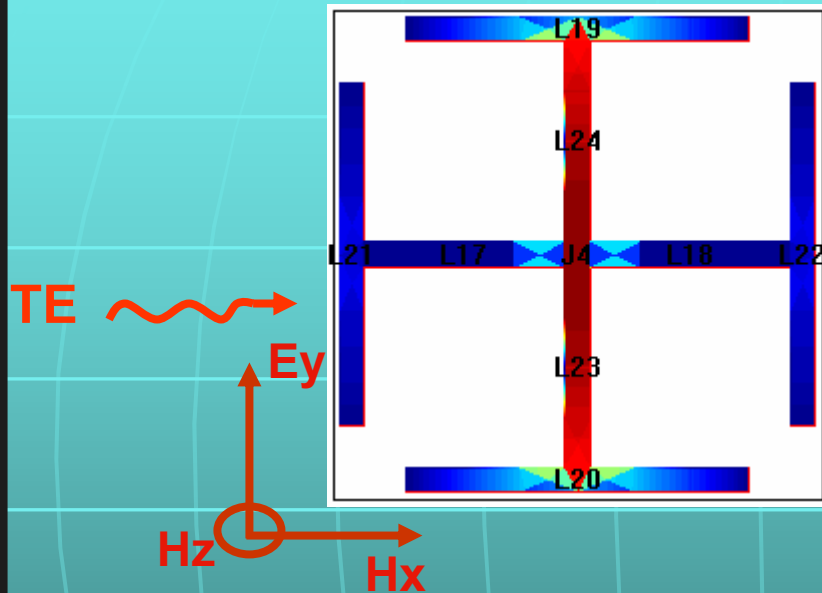
$h = w = 0.2 \text{ mm}$

substrate thickness is 6 mm

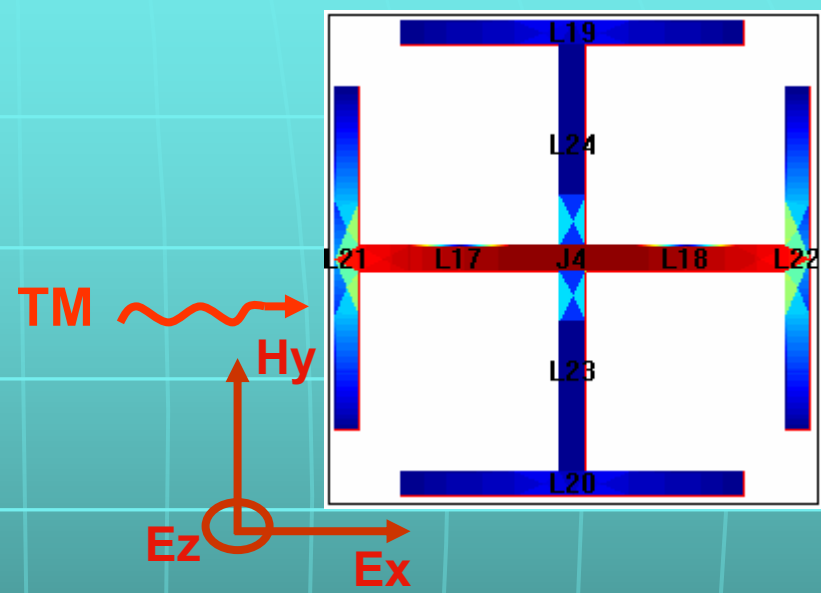
dielectric permittivity is 2.7

Current Distribution

TE Polarization



TM Polarization

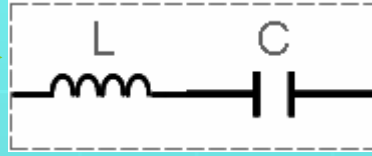
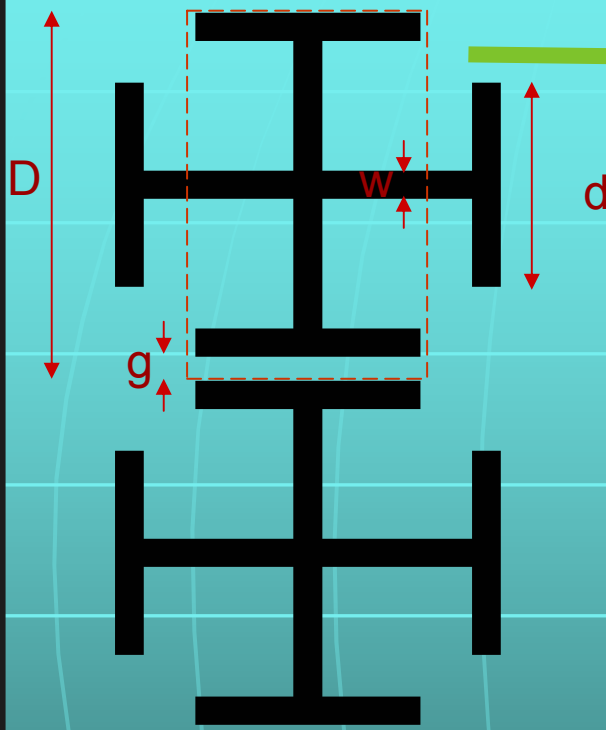


➤ Current distribution of Jerusalem cross at 4.808 GHz

$$Z_g^{TE}(\omega, \theta) = Z_{g,L}^{TE}(\omega, 0) + Z_{g,C}^{TE}(\omega, 0)$$

$$Z_g^{TM}(\omega, \theta) = Z_{g,L}^{TM}(\omega, 0) \left(1 - 2 \frac{\sin^2 \theta}{\epsilon_r + 1} \right) + Z_{g,C}^{TM}(\omega, 0)$$

Effective Inductance & Capacitance



$$Z_{g,L}^{TE}(\omega, 0) = Z_{g,L}^{TM}(\omega, 0) = j\omega L_g$$

$$Z_{g,C}^{TE}(\omega, 0) = Z_{g,C}^{TM}(\omega, 0) = 1 / j\omega C_g$$

Here:

$$g = \frac{\eta_0 \alpha}{2\omega \sqrt{\epsilon_{eff}}}$$

$$C_g = \frac{1}{\pi} \epsilon_0 \epsilon_r d \left[\ln \csc \left(\frac{\pi g}{2D} \right) + F \right]$$

Where

$$\alpha = \frac{kD}{\pi} \log \left(\frac{2D}{\pi w} \right)$$

$$F = \frac{Qu^2}{1+Q(1-u)^2} + \left(\frac{du(3u-2)}{4\lambda} \right)^2$$

$$Q = \sqrt{1 - \left(\frac{d}{\lambda} \right)^2}$$

$$u = \cos^2 \frac{\pi g}{2d}$$

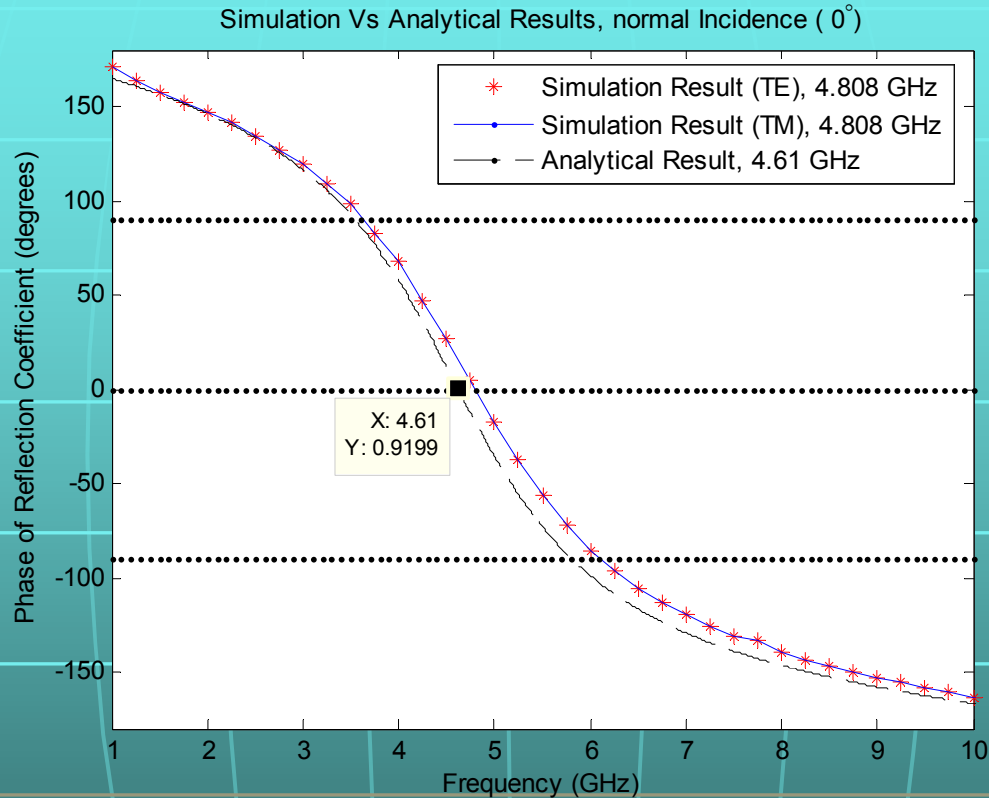
$$\lambda = \frac{2\pi}{k}$$

C. R. Simovski, P. de Maagt, and I. V. Melchakova, "High-impedance surfaces having stable resonance with respect to polarization and incidence angle," *IEEE Trans. Antennas Propagat.*, Vol. 53, no. 3, pp. 908-914, Mar. 2005

S. A. Tretyakov, *Analytical Modeling in Applied Electromagnetics*, Boston, MA: Artech House, 2003

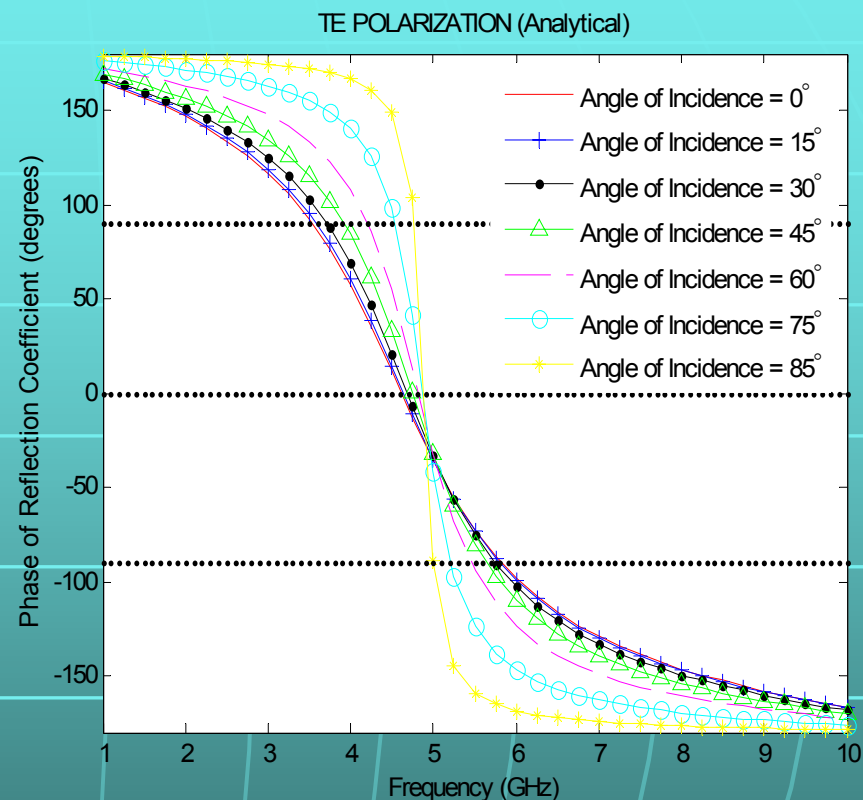
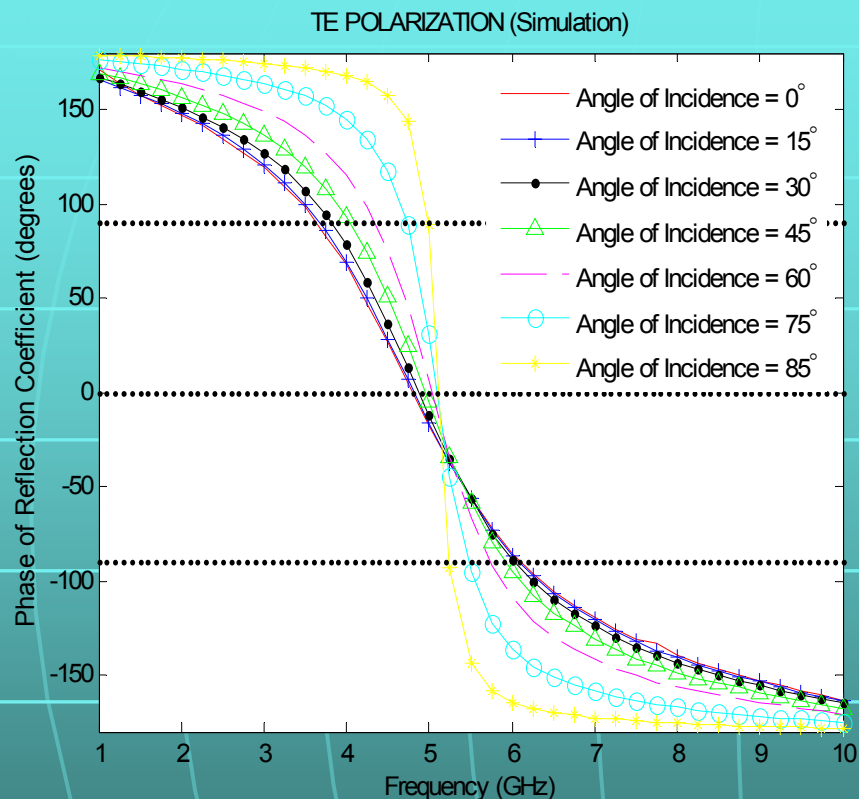
N. Marcuvitz, *Waveguide Handbook*, Peter Peregrinus Ltd, 1986

Simulation Vs Analytical Model



Analytical model agrees well with the full wave results by EMPiCASSO

Oblique Incidence (TE Polarization)



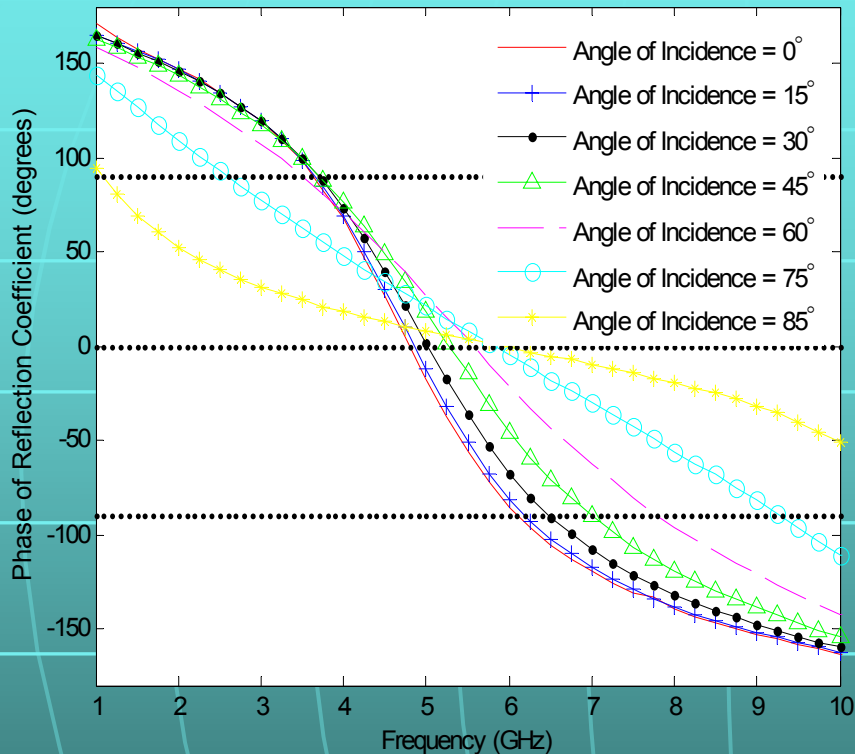
Shift in resonance frequency,

Simulation = $(5.122 - 4.808)$ GHz = 0.314 GHz

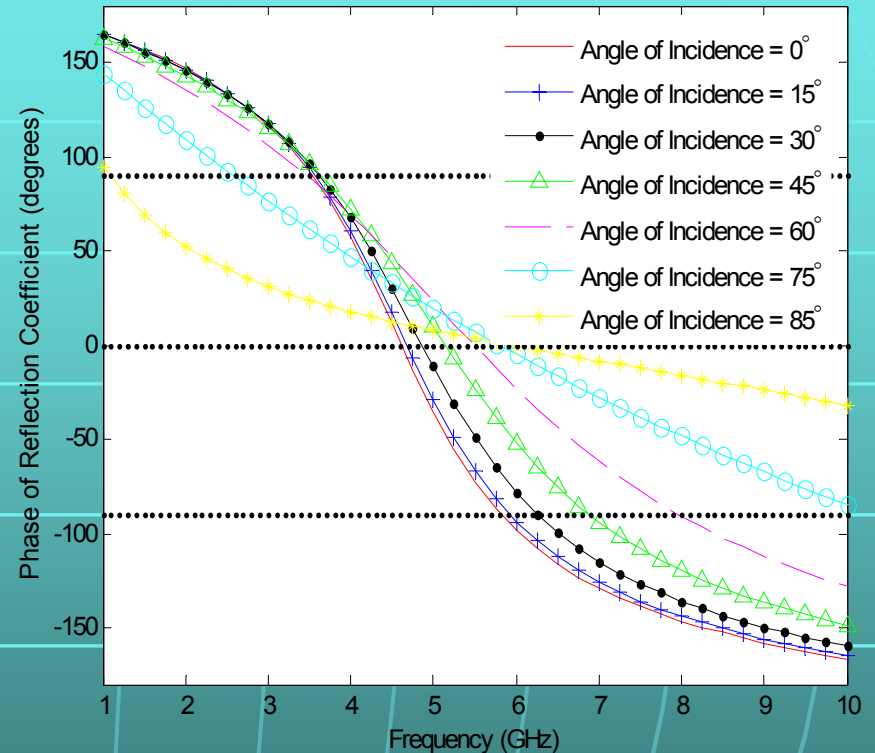
Analytical = $(4.89 - 4.61)$ GHz = 0.28 GHz

Oblique Incidence (TM)

TM POLARIZATION (Simulation)



TM POLARIZATION (Analytical)

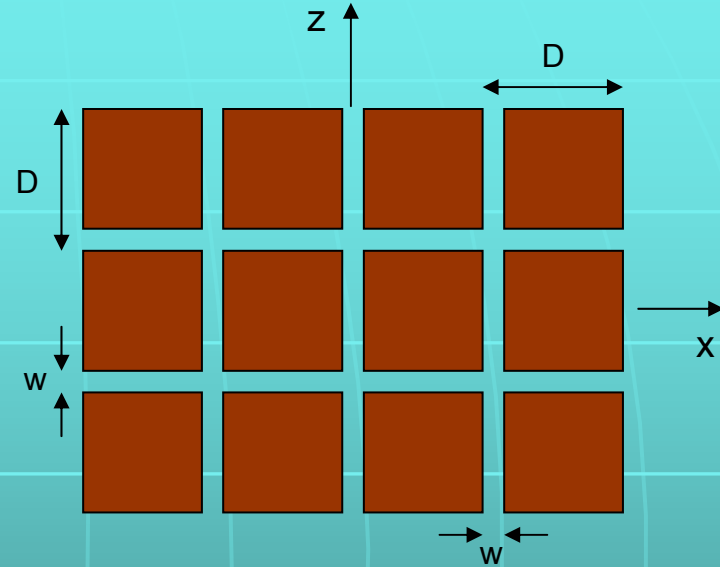
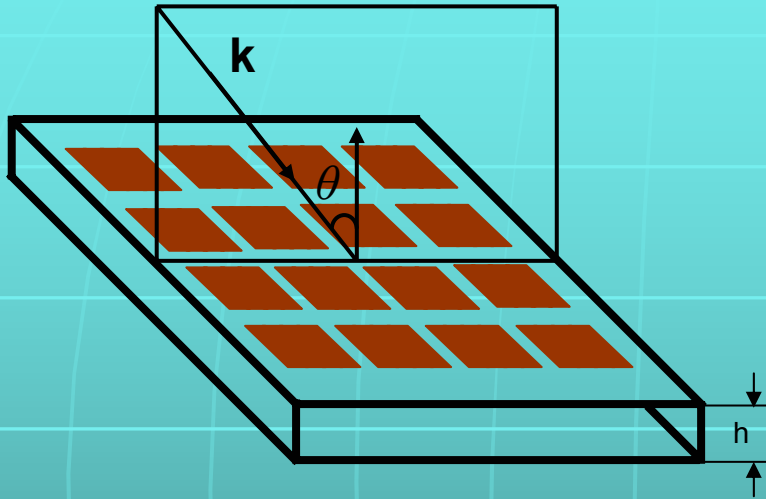


Shift in resonance frequency,

Simulation = (5.885 - 4.808) GHz = 1.077 GHz

Analytical = (5.89 - 4.808) GHz = 1.082 GHz

Patch Array



Grid impedance

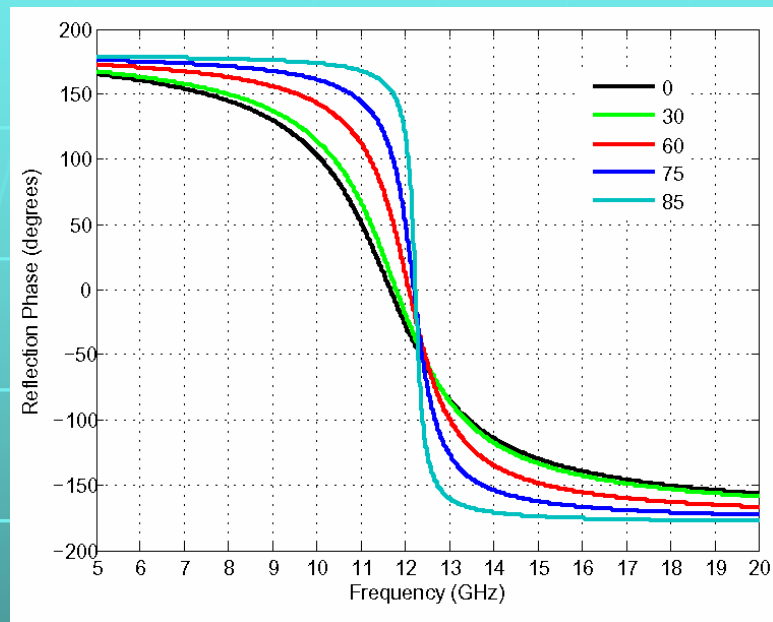
- Quasi-static solution of 2D strip grid scattering problem
- Averaged impedance boundary condition
- Approximate Babinet principle

$$Z_g^{TE} = -j \frac{\eta_{eff}}{2\alpha} \frac{1}{\left(1 - \frac{1}{2} \frac{k_0^2}{k_{eff}^2} \sin^2 \theta\right)}$$

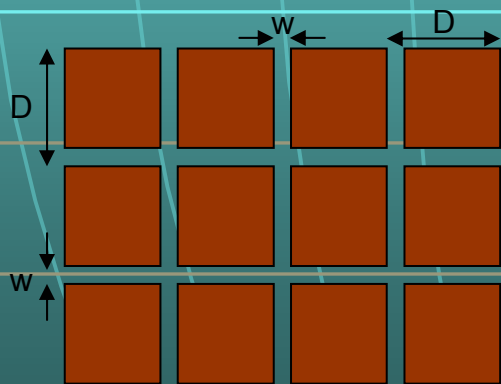
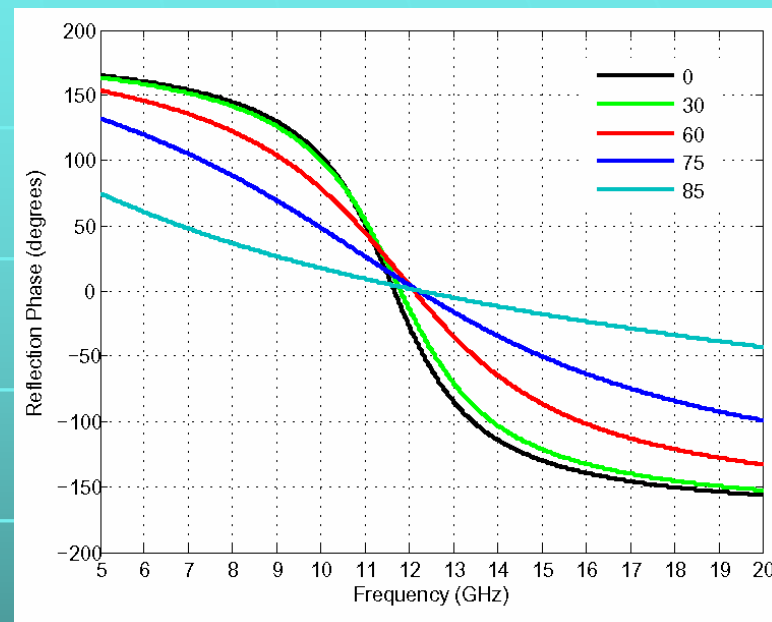
$$Z_g^{TM} = -j \frac{\eta_{eff}}{2\alpha} \quad \alpha = \frac{k_{eff} D}{\pi} \ln \left(\csc \left(\frac{\pi w}{2D} \right) \right)$$

Oblique Incidence

TE polarization

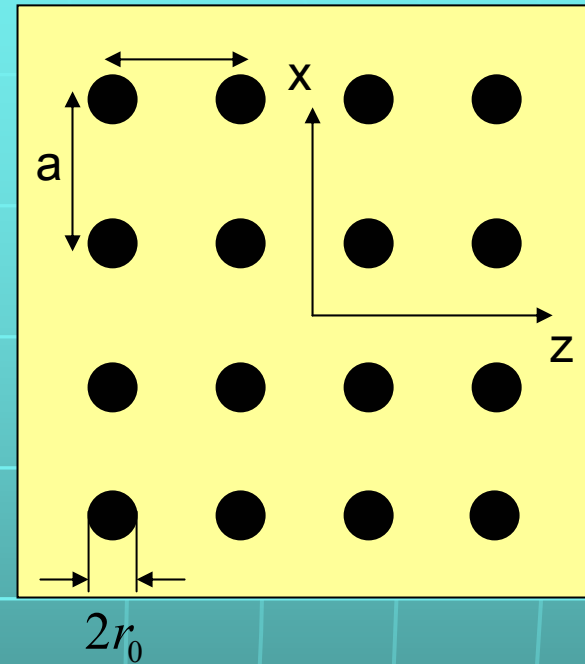
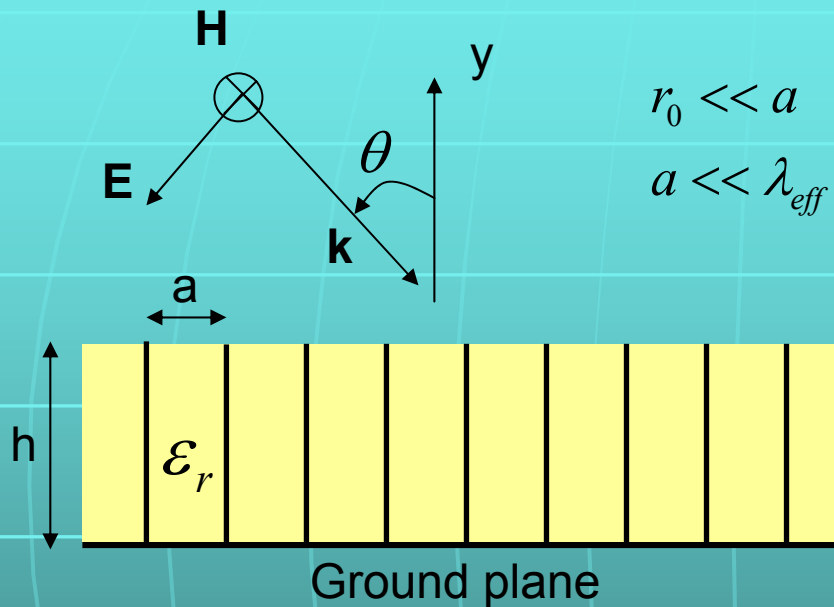


TM polarization



$D = 2 \text{ mm}$, $w = 0.2 \text{ mm}$
substrate thickness is 1 mm
dielectric permittivity is 10.2

Wire Media Slab



Anisotropic material characterized by effective permittivity
 Quasi-static approximation

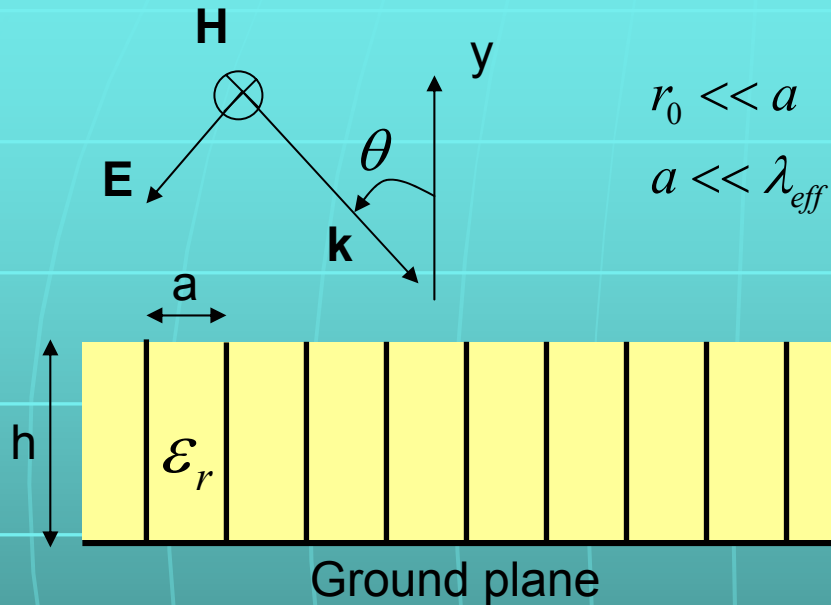
$$\vec{\epsilon}_{eff} = \epsilon_0 \epsilon_r \left(\hat{x}\hat{x} + \epsilon_{yy} \hat{y}\hat{y} + \hat{z}\hat{z} \right)$$

$$\epsilon_{yy} = 1 - \frac{k_p^2}{k_0^2 \epsilon_r}$$

k_p is the plasma wavenumber

$$k_p^2 = \frac{2\pi / a^2}{\ln \left(\frac{a^2}{4r_0(a-r_0)} \right)}$$

Surface Impedance of Wire Media Slab



Impedance boundary condition at $y=h$:

$$\vec{E}_t = j\omega\mu_0 \frac{\tan(k_{yd}h)}{k_{yd}} \left(1 - \frac{k_z^2}{k_0^2 \epsilon_{yy}}\right) \hat{n} \times \vec{H}_t$$

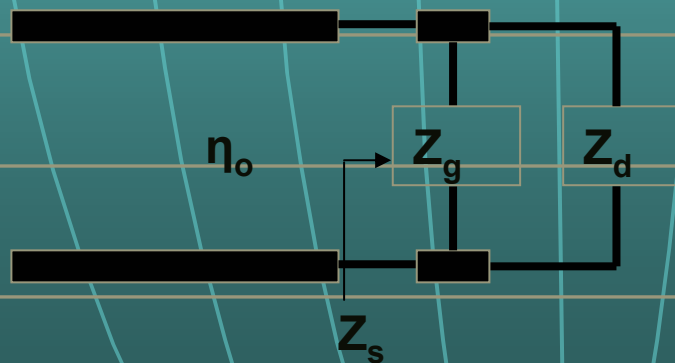
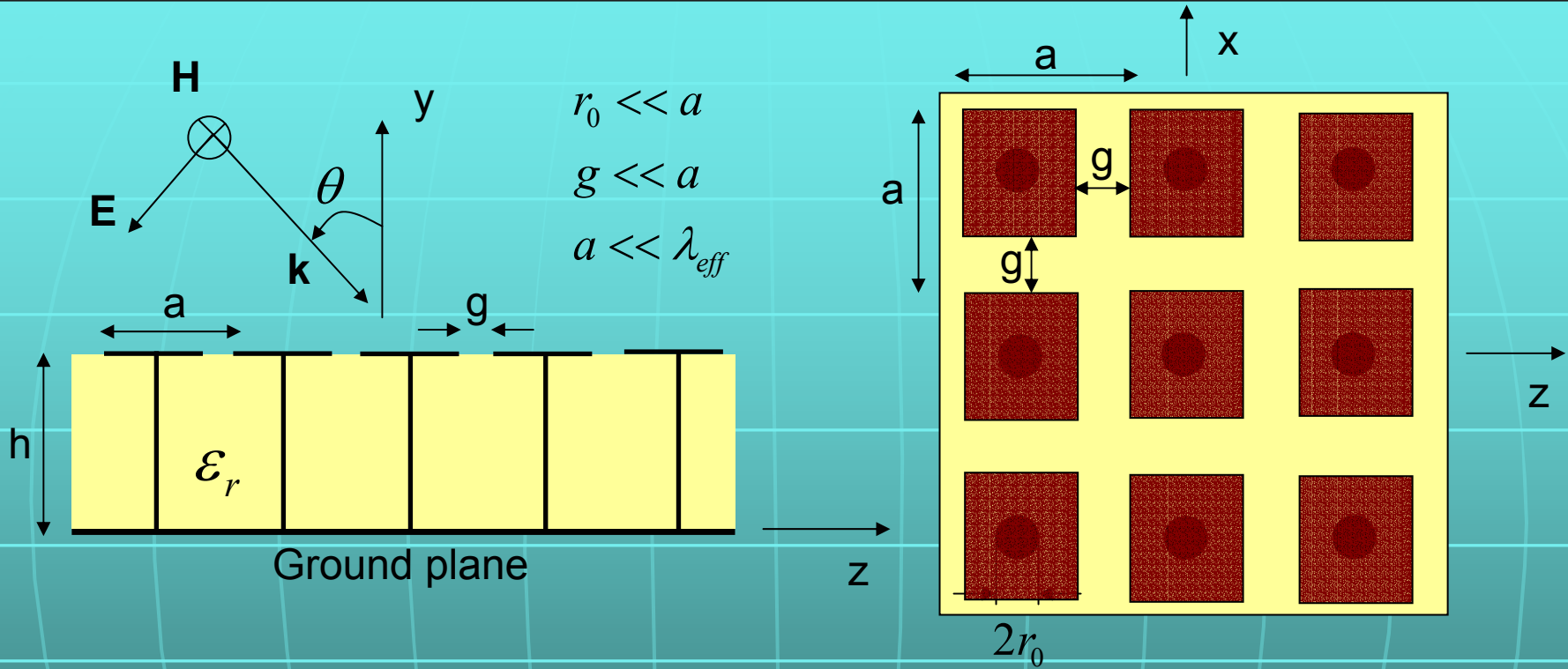
Surface impedance

$$Z_d^{TM} = j\omega\mu_0 \frac{\tan(k_{yd}h)}{k_{yd}} \frac{k_0^2 \epsilon_r - k_p^2 - k_z^2}{k_0^2 \epsilon_r - k_p^2}$$

$$k_{yd} = \sqrt{k_0^2 \epsilon_r - \frac{\epsilon_r}{\epsilon_{yy}} k_z^2}$$

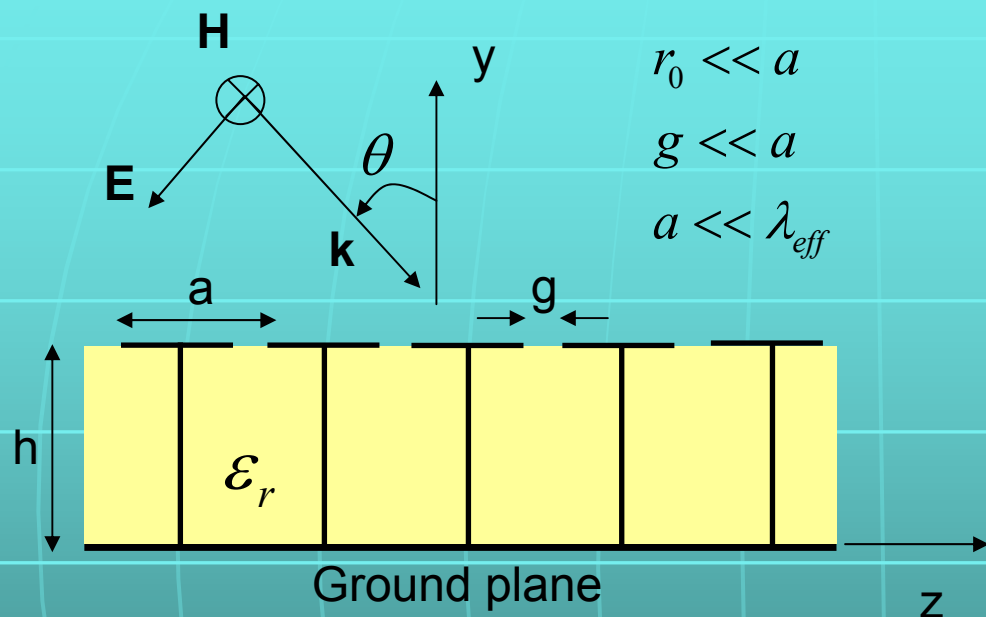
$$\epsilon_{yy} = 1 - \frac{k_p^2}{k_0^2 \epsilon_r}$$

Mushroom Array

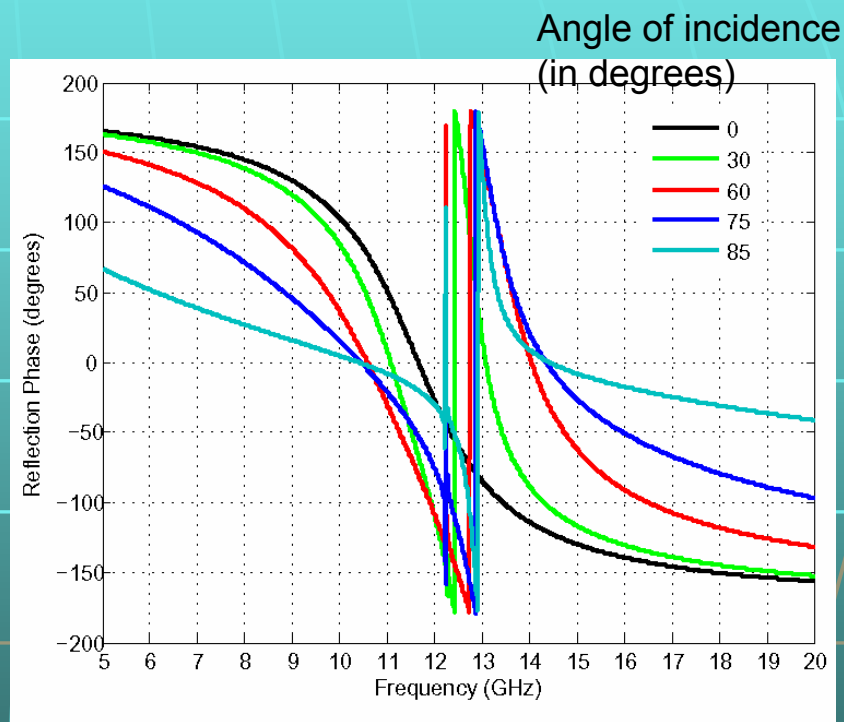


$$Z_s = \frac{Z_g Z_d}{Z_g + Z_d}$$

Mushroom Array

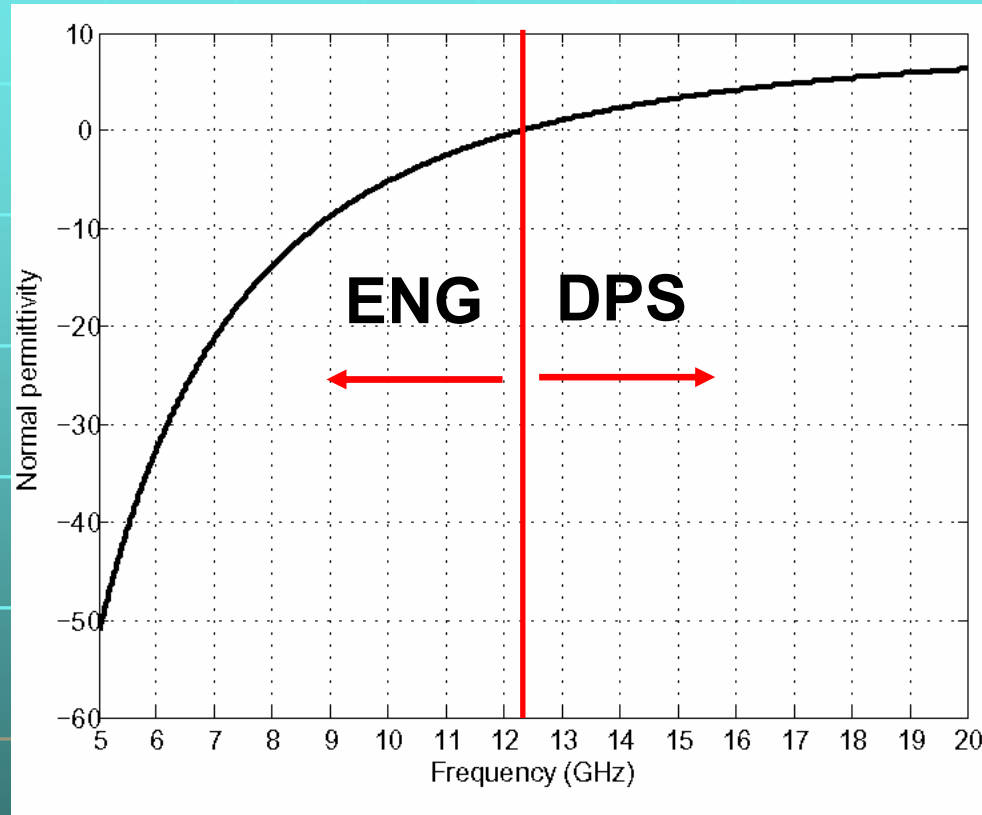


TM polarization



Period of vias is 2 mm
Period of patches is 2 mm
Gap is 0.2 mm
Radius of vias is 0.05 mm
Substrate thickness is 1 mm
Dielectric permittivity is 10.2

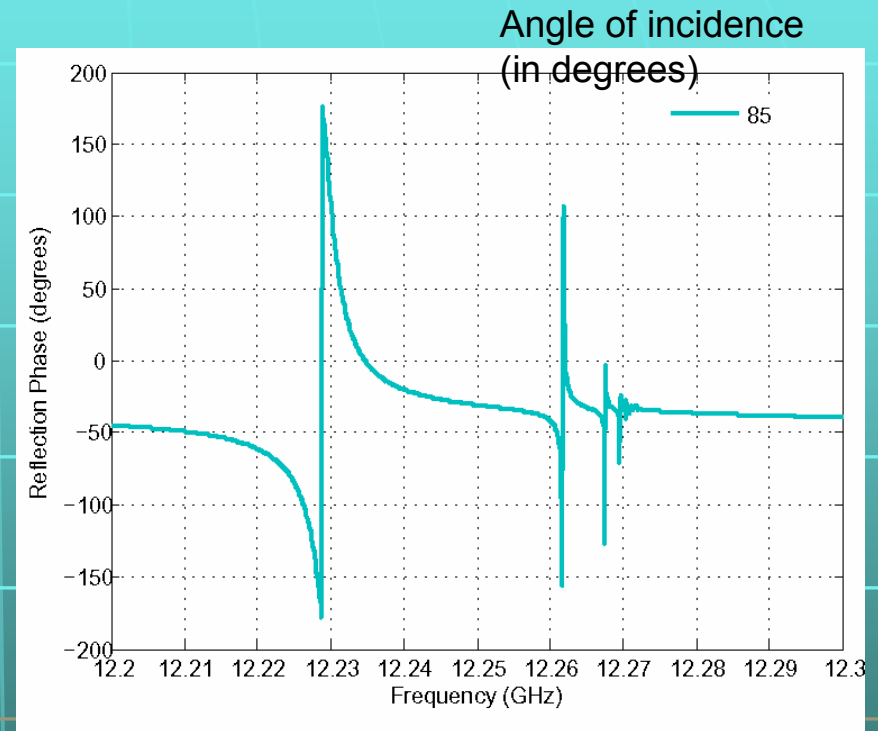
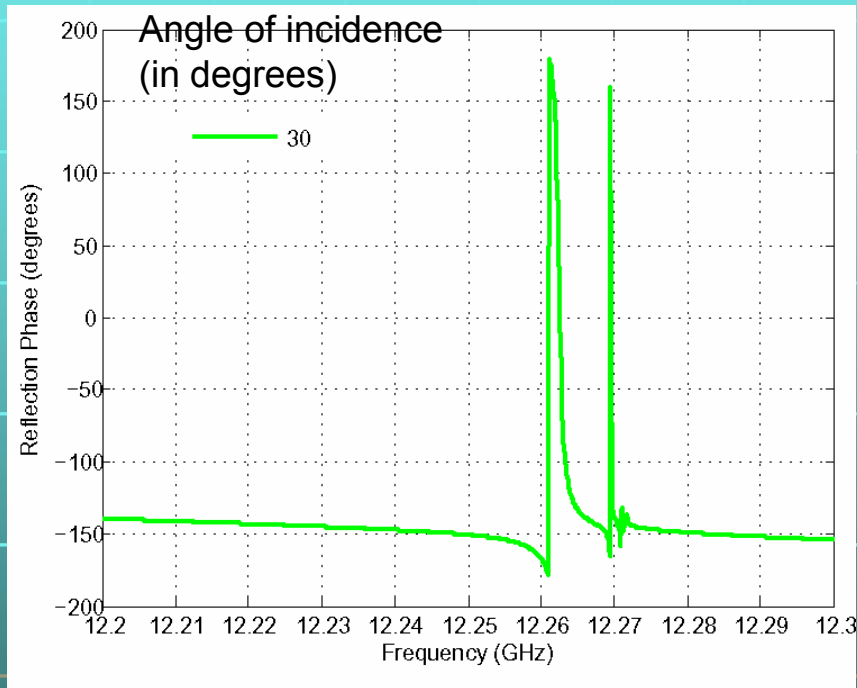
Effective Permittivity Along the Vias



Wire media slabs and mushroom structures support backward waves in the ENG frequency band

Plane-Wave Interaction

TM polarization



Multiple resonances occur in a narrow frequency band close to the transition of effective media from ENG to DPS. These resonances are due to coupling of plane-wave to higher-order modes excited close to the transition point.

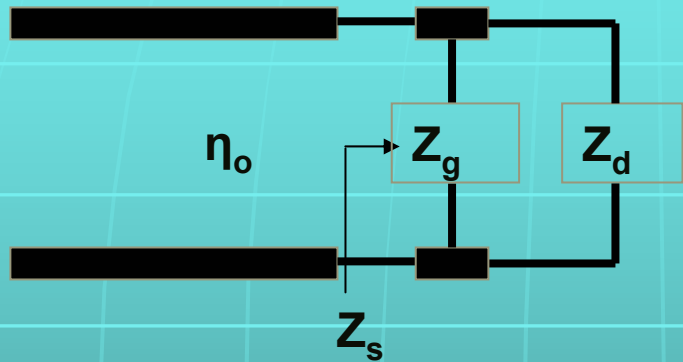
Part II

Outline

- **Model 1 – Impedance Surface**
- **Model 2 – Grounded Dielectric Slab with Grid Impedance**
 - ✓ Dispersion equations for surface waves
 - ✓ Dispersion behavior of proper and improper TE and TM surface waves
- **Conclusion**

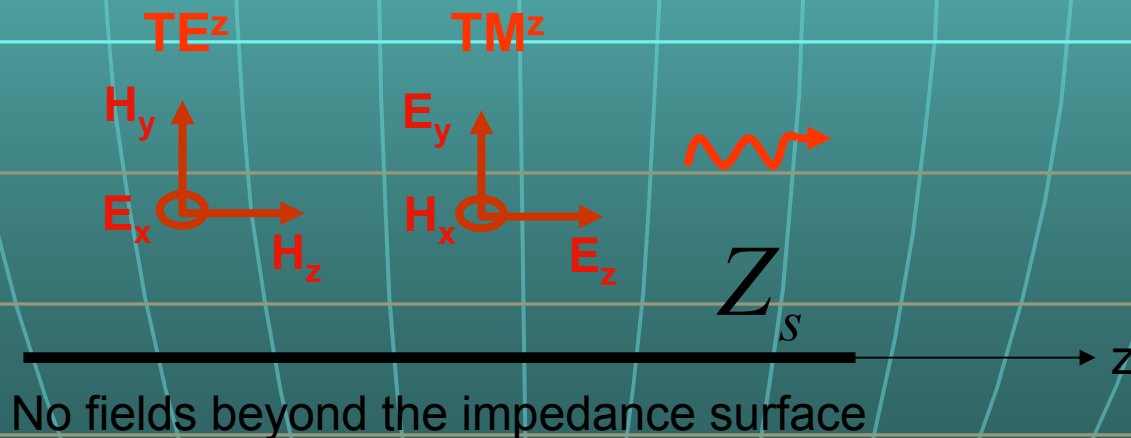
Model 1 – Impedance Surface

Transmission Line Model



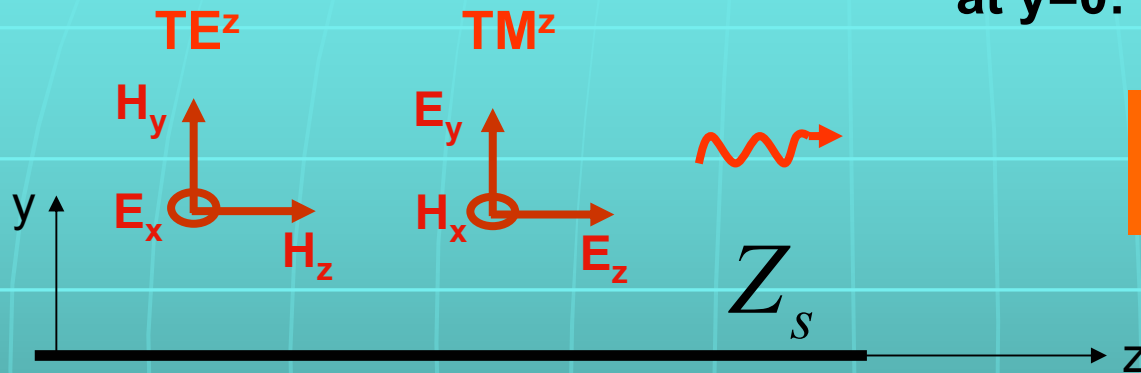
$$Z_s = \frac{Z_g Z_d}{Z_g + Z_d}$$

Impedance Surface Model



Model 1 – Impedance Surface

Impedance Surface Model



Impedance Boundary Condition at $y=0$:

$$\vec{E} = Z_s \hat{y} \times \vec{H}$$

No fields beyond the impedance surface

TE^z

$$E_x = Z_s^{TE} H_z \quad E_x = E_0 e^{-jk_z^{TE} z - k_y^{TE} y}$$

$$k_y^{TE} = -\frac{j\omega\mu_0}{Z_s^{TE}} \quad k_z^{TE} = k_0 \sqrt{1 - \left(\frac{\eta_0}{Z_s^{TE}}\right)^2}$$

TM^z

$$E_z = -Z_s^{TM} H_x \quad H_x = H_0 e^{-jk_z^{TM} z - k_y^{TM} y}$$

$$k_y^{TM} = -j\omega\varepsilon_0 Z_s^{TM} \quad k_z^{TM} = k_0 \sqrt{1 - \left(\frac{Z_s^{TM}}{\eta_0}\right)^2}$$

Surface Waves

$$Z_s = \frac{Z_g Z_d}{Z_g + Z_d}$$

$$Z_d^{TE}(\omega, \theta) = \frac{j\eta_0}{\sqrt{\epsilon_r - \sin^2 \theta}} \tan(k_{zd} h)$$

$$Z_d^{TM}(\omega, \theta) = \frac{j\eta_0}{\sqrt{\epsilon_r - \sin^2 \theta}} \tan(k_{zd} h) \left(1 - \frac{\sin^2 \theta}{\epsilon_r} \right)$$

$$Z_g^{TE}(\omega, \theta) = Z_{g,L}^{TE}(\omega, \theta) + Z_{g,C}^{TE}(\omega, \theta)$$

$$Z_g^{TM}(\omega, \theta) = Z_{g,L}^{TM}(\omega, \theta) + Z_{g,C}^{TM}(\omega, \theta)$$

$$\sin(\theta) = \frac{k_z}{k_0}$$

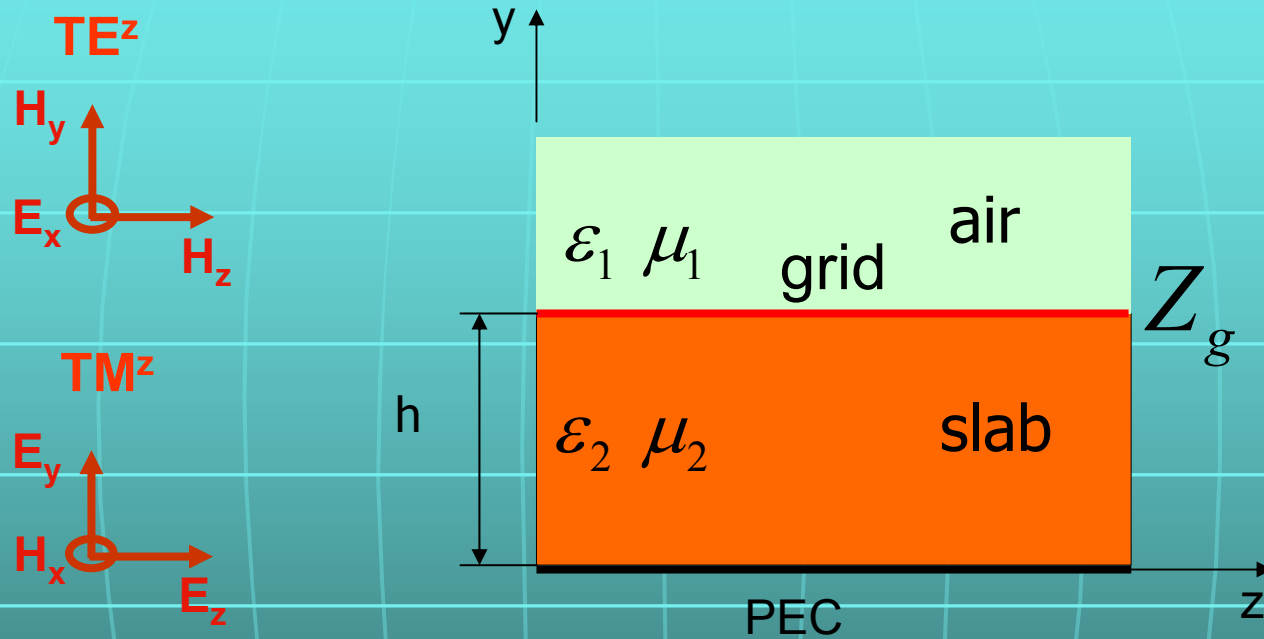


$$Z_s \equiv Z_s(k_z)$$

$$k_z^{TE} = k_0 \sqrt{1 - \left(\frac{\eta_0}{Z_s^{TE}(k_z^{TE})} \right)^2}$$

$$k_z^{TM} = k_0 \sqrt{1 - \left(\frac{Z_s^{TM}(k_z^{TM})}{\eta_0} \right)^2}$$

Model 2 – Grounded Dielectric Slab with Grid Impedance on Air-Dielectric Interface



Two-sided impedance boundary condition at $y=h$

$$\vec{E}_1 = \vec{E}_2 = Z_g \hat{y} \times (\vec{H}_1 - \vec{H}_2)$$

Dispersion Equations

Two-sided impedance boundary condition at $y=h$

TE^z-odd

$$E_{x1} = E_{x2} = Z_g^{TE} (H_{z1} - H_{z2})$$

TM^z-even

$$E_{z1} = E_{z2} = -Z_g^{TM} (H_{x1} - H_{x2})$$

Dispersion equations

$$\frac{\mu_2}{\mu_1} k_{y1} + k_{y2} \coth(k_{y2}h) = -\frac{j\omega\mu_2}{Z_g^{TE}}$$

$$k_{y2} \tanh(k_{y2}h) = -Z_g^{TM} \frac{j\omega\varepsilon_2 k_{y1}}{j\omega\varepsilon_1 Z_g^{TM} + k_{y1}}$$

Complex Wavenumber Plane

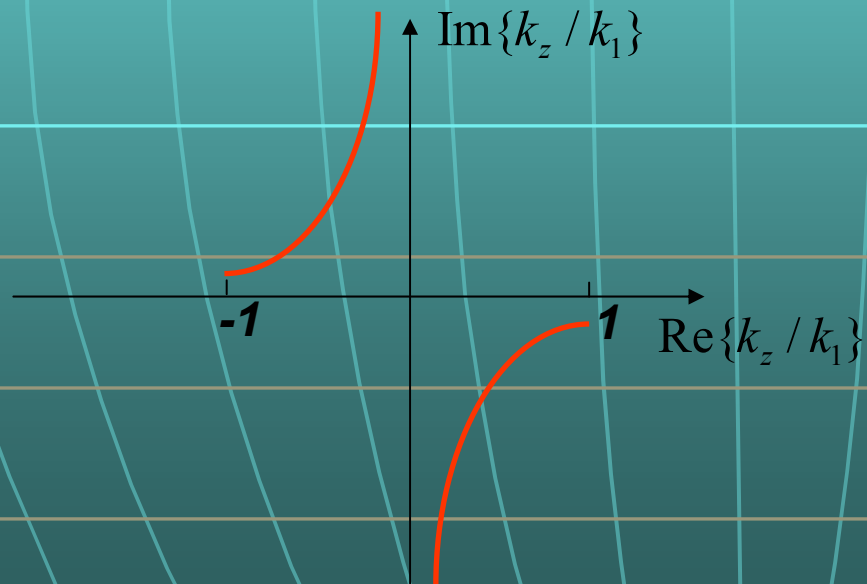
Branch points in the complex k_z -plane at $k_z = \pm k_1$

$\text{Re}\{k_{y1}\} > 0$ - proper modes on the top Riemann sheet

$\text{Re}\{k_{y1}\} < 0$ - improper modes on the bottom Riemann sheet

$\text{Re}\{k_{y1}\} = 0$ - branch cuts condition

Hyperbolic k_z -plane branch cuts:



$$\text{Im}\{k_z\} = \frac{\text{Im}\{k_1\} \text{Re}\{k_1\}}{\text{Re}\{k_z\}}$$

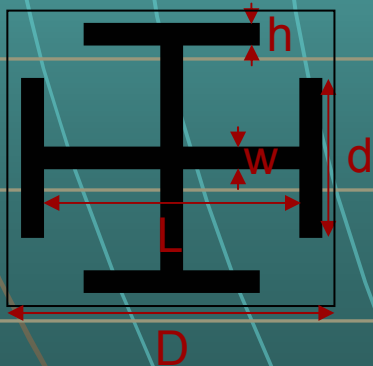
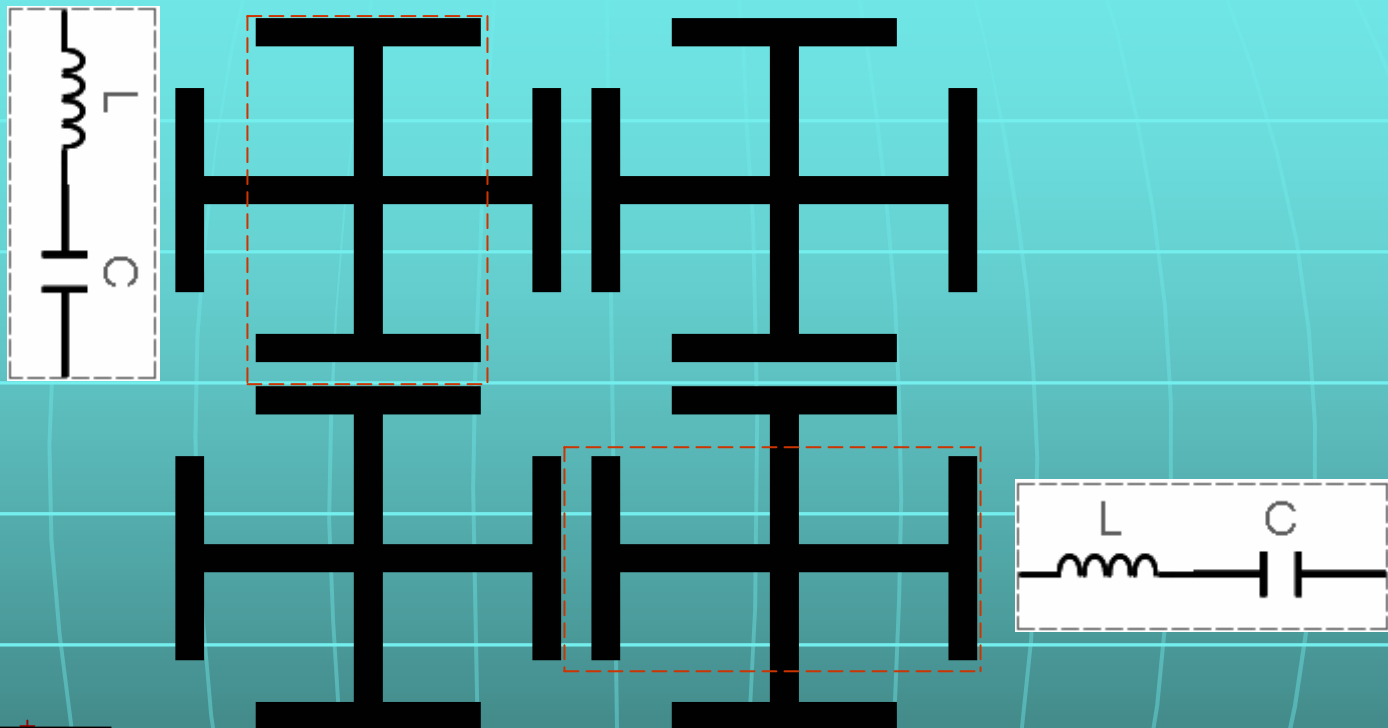
$$|\text{Re}\{k_z\}| < |\text{Re}\{k_1\}|$$

$$k_{y_i} = \sqrt{k_z^2 - k_i^2}$$

$$k_i^2 = n_i^2 \left(\frac{\omega}{c} \right)^2$$

$$c = (\mu_0 \epsilon_0)^{-1/2}$$

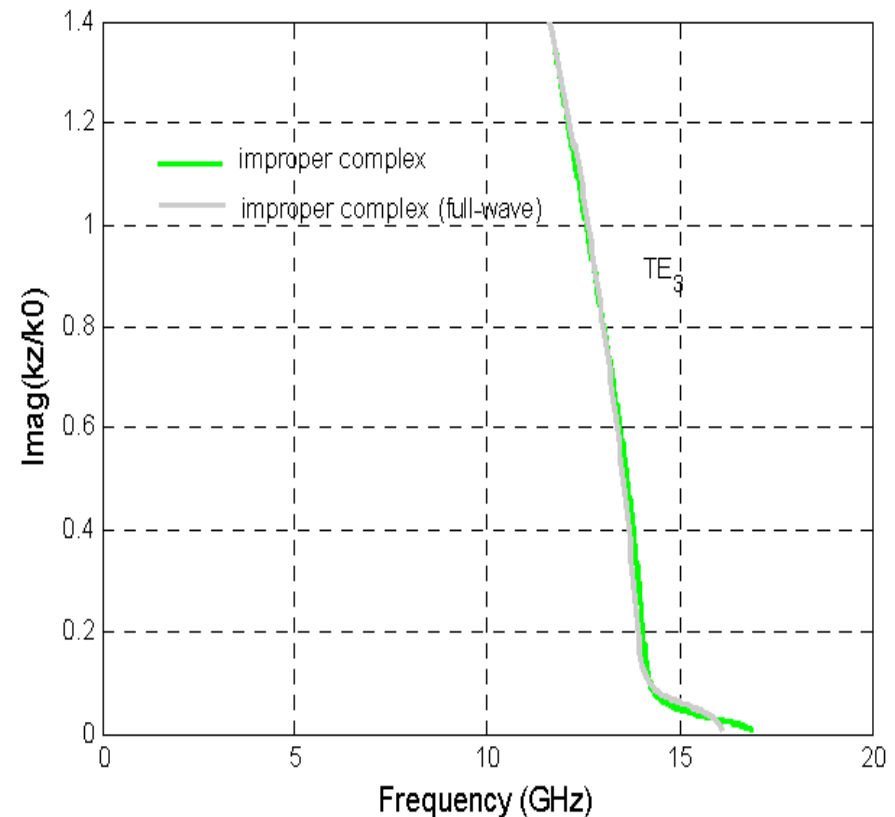
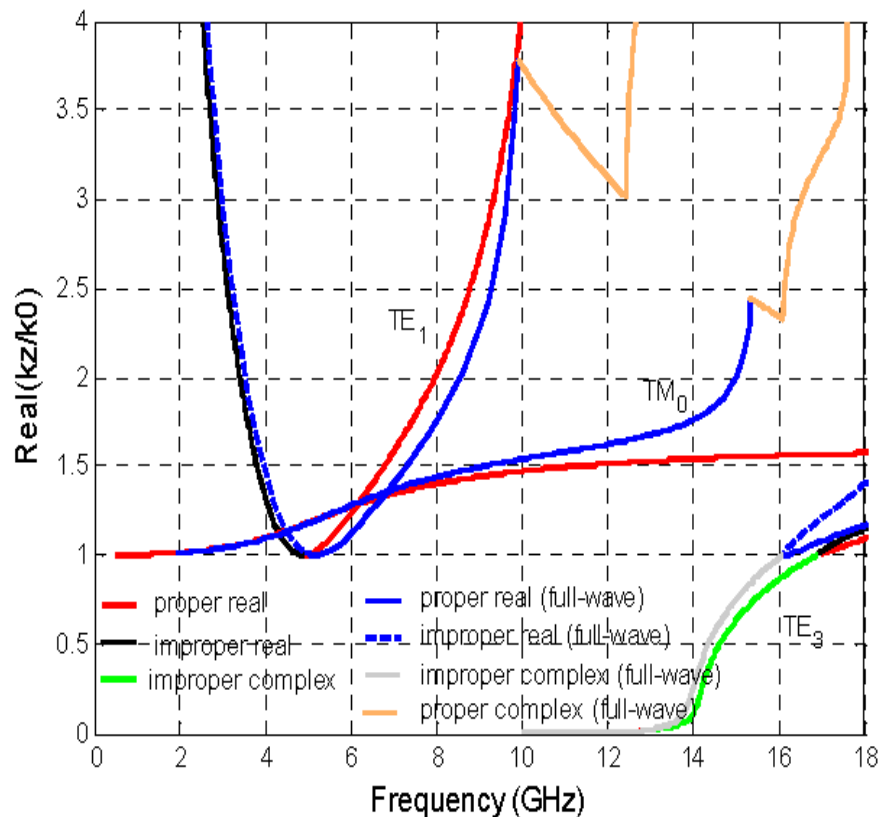
Jerusalem Cross Array



$D = 4 \text{ mm}$, $d = 2.8 \text{ mm}$,
 $h = w = 0.2 \text{ mm}$, $L = 3.5 \text{ mm}$
substrate thickness is 6 mm
dielectric permittivity is 2.7

Dispersion Behavior of Surface Waves

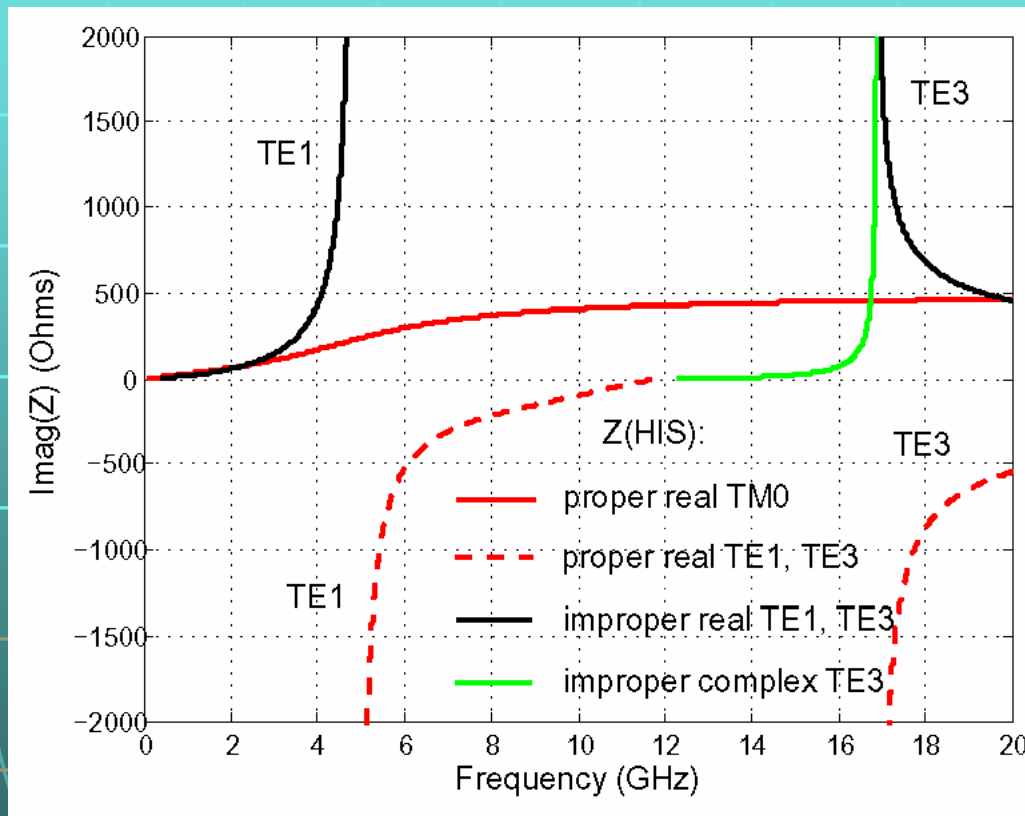
Jerusalem cross HIS structure Comparison with full-wave results



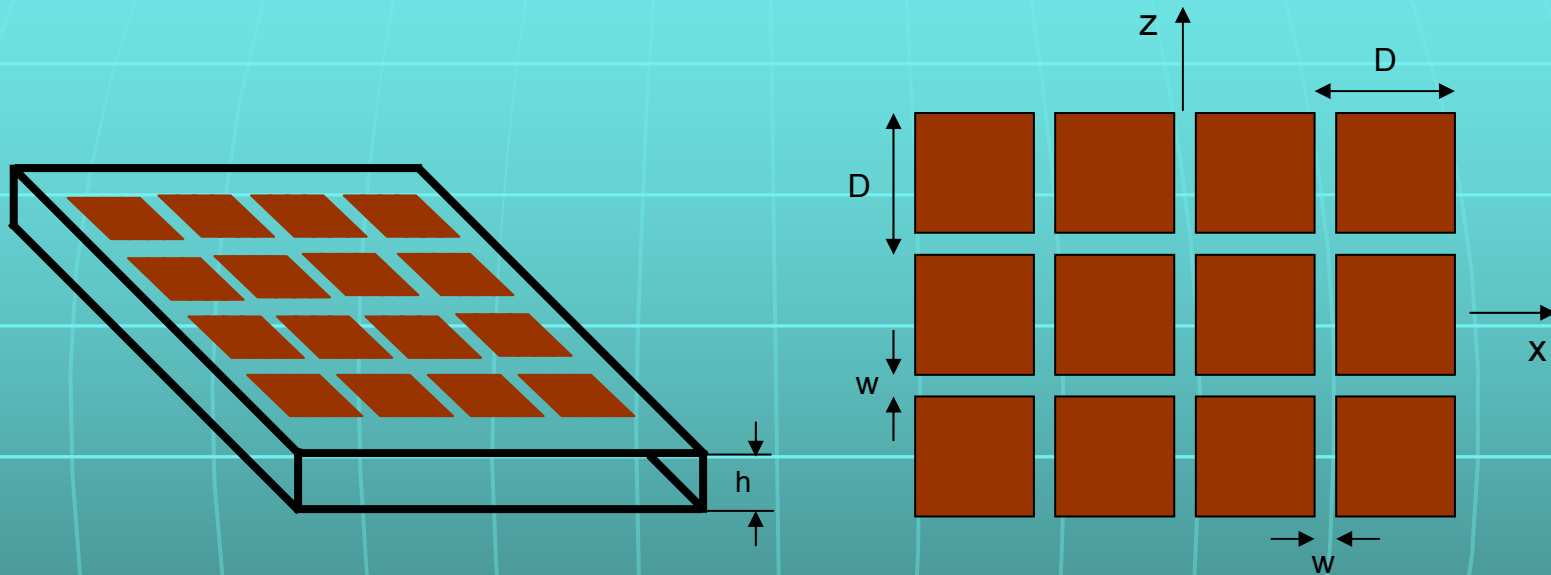
Surface Impedance of HIS

Jerusalem cross HIS structure

Surface impedance of HIS “seen” by surface waves



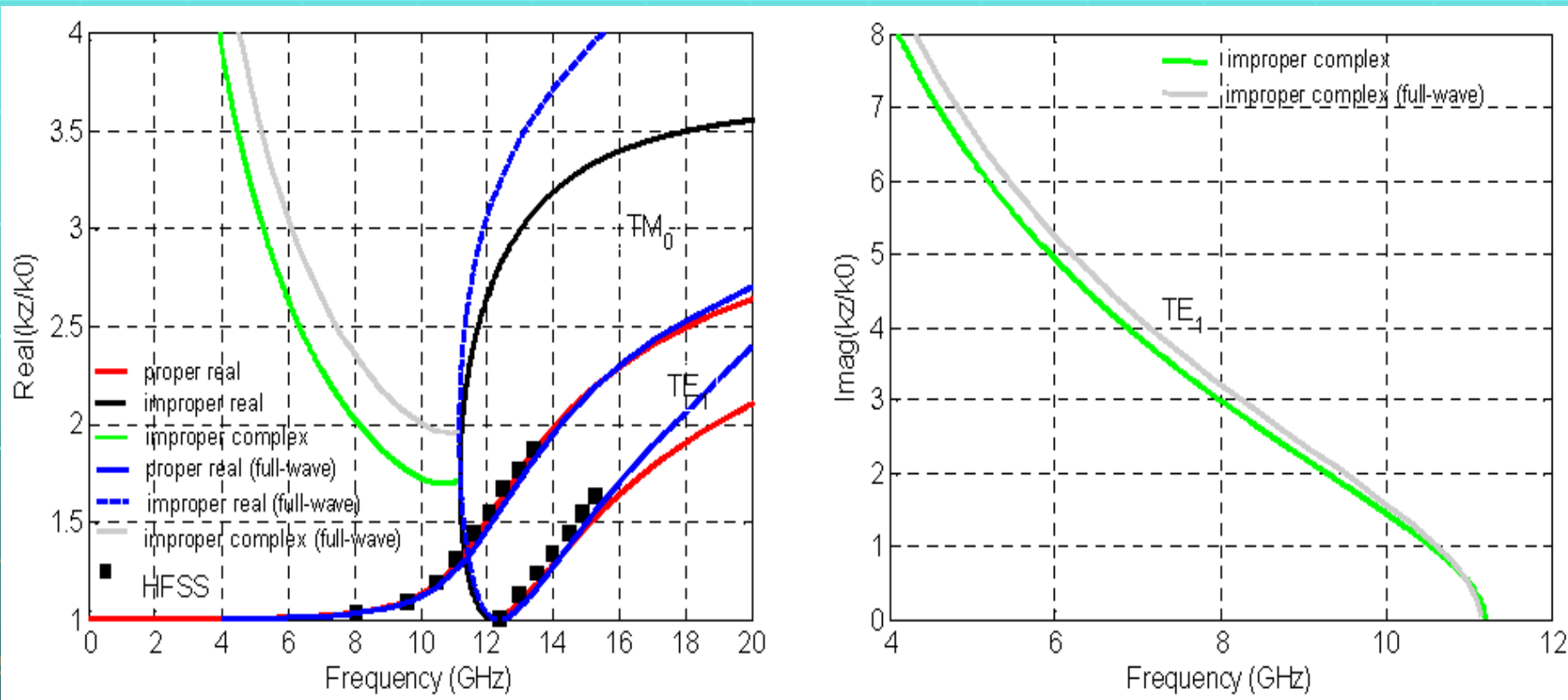
Patch Array



$D = 2 \text{ mm}$, $w = 0.2 \text{ mm}$
substrate thickness is 1 mm
dielectric permittivity is 10.2

Dispersion Behavior of Surface Waves

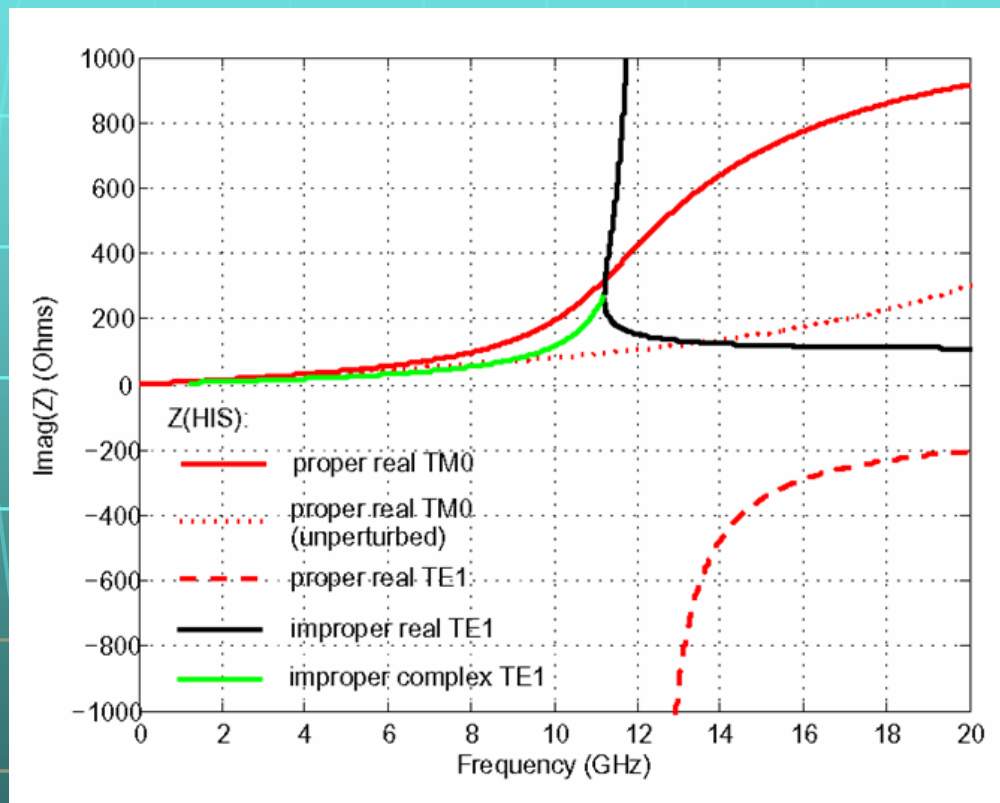
Patch HIS structure Comparison with full-wave results



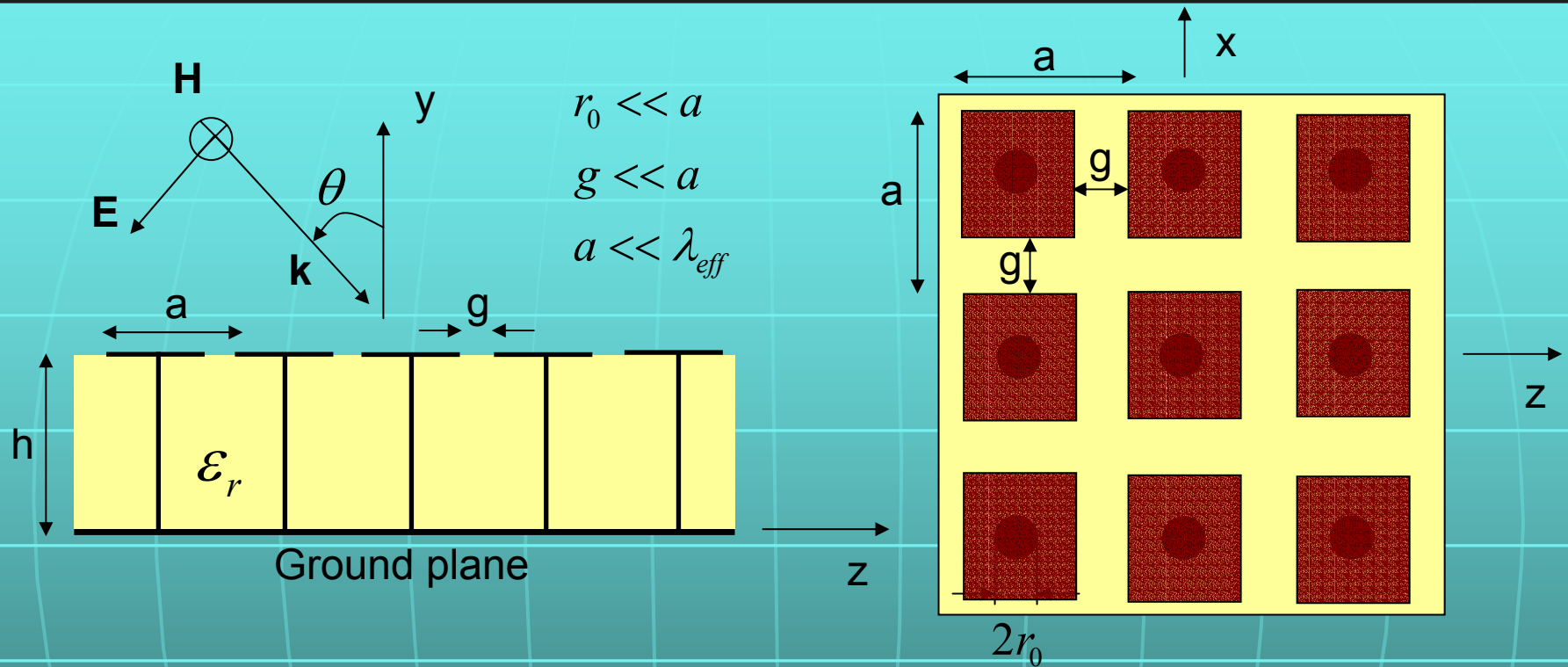
Surface Impedance of HIS

Patch HIS structure

Surface impedance of HIS “seen” by surface waves



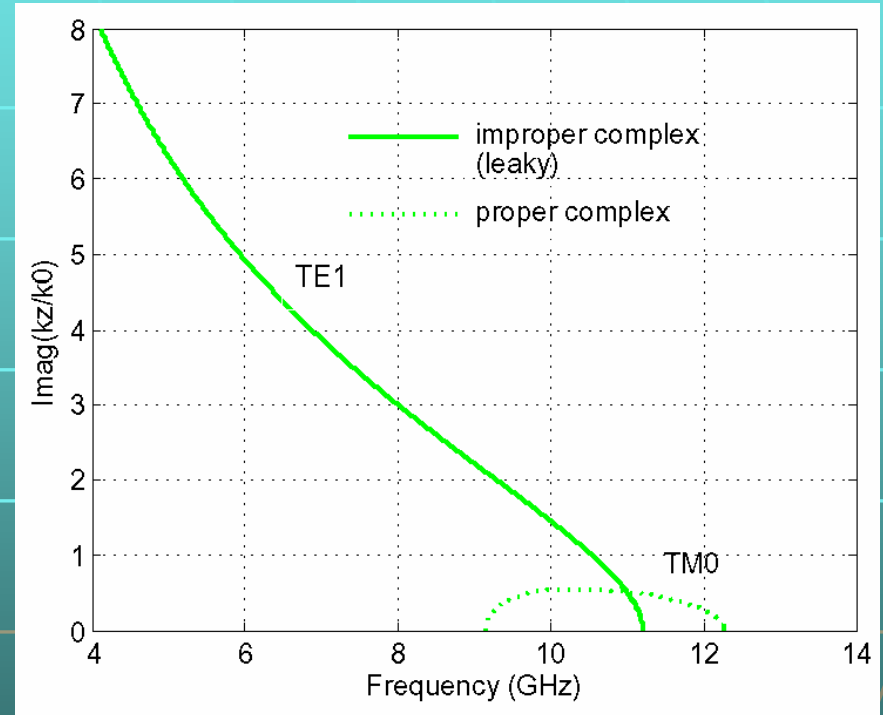
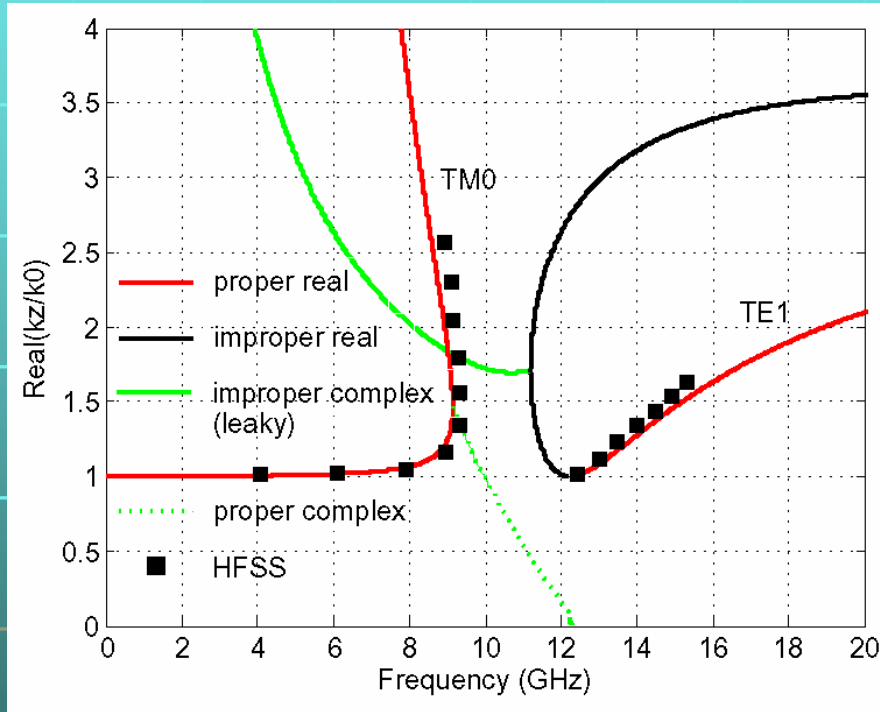
Mushroom Array



Period of vias is 2 mm
Period of patches is 2 mm
Gap is 0.2 mm
Radius of vias is 0.05 mm
Substrate thickness is 1 mm
Dielectric permittivity is 10.2

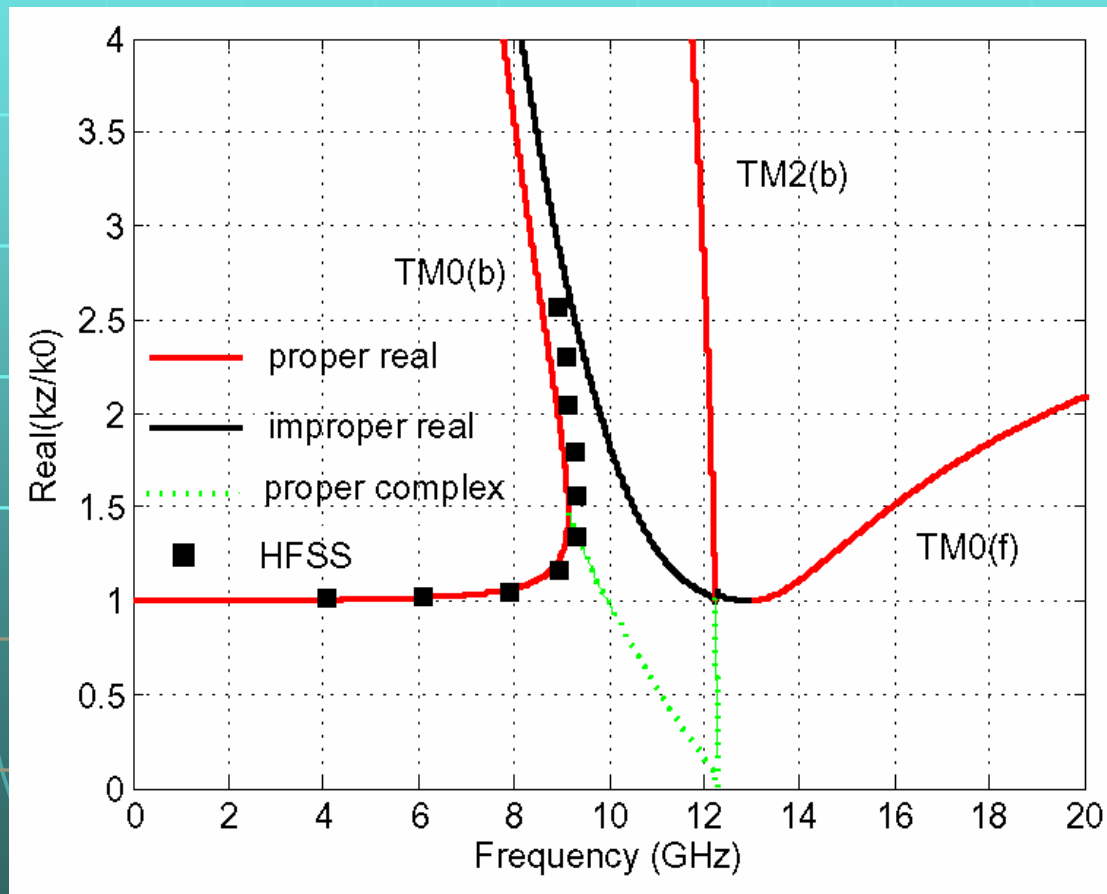
Dispersion Behavior of Surface Waves

Mushroom HIS structure Comparison with full-wave results



TM Surface Waves

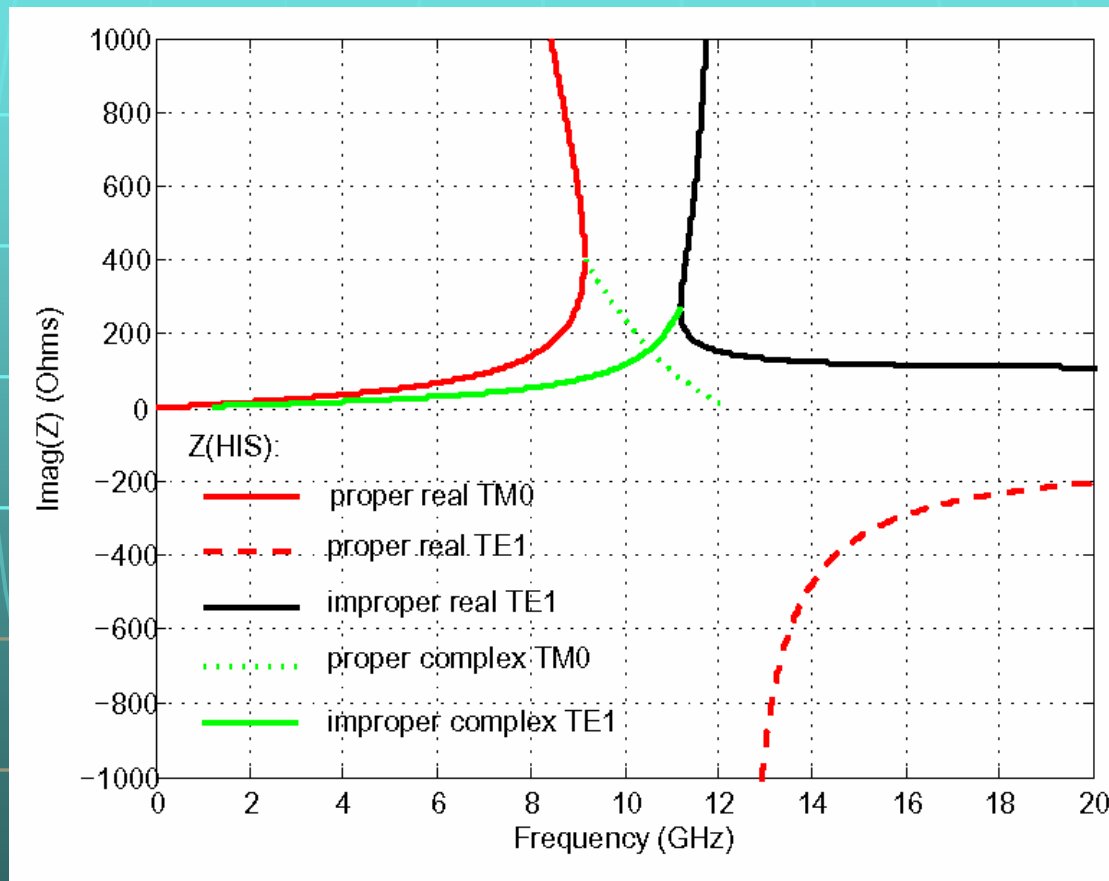
Mushroom HIS structure Higher-order TM backward waves



Surface Impedance of HIS

Mushroom HIS structure

Surface impedance of HIS “seen” by surface waves



Conclusion

- **Accurate and rapid analysis of plane-wave interaction and surface-wave propagation on dense HIS structures**
- **Analytical modeling is based on the quasi-static approximation of full-wave scattering problem via the averaged impedance boundary condition. A homogenized surface grid impedance is expressed in terms of effective circuit parameters**
- **It is observed that in dense HIS structures no stopband between TE and TM surface-wave modes occurs at low frequencies. This is in contrast to conventional FSS structures, wherein stopbands occur due to Bragg's diffraction at resonance frequency**
- **Stopbands in mushroom HIS structures at low frequencies are due to backward waves associated with wire media slab**

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